xDSL/Cable Modem Triple/Quintuple Output Power Supplies


#### Abstract

General Description The MAX1864/MAX1865 power-supply controllers are designed to address cost-conscious applications such as cable modem Consumer Premise Equipment (CPE), xDSL CPE, and set-top boxes. Operating off a low-cost, unregulated DC supply (such as a wall adapter output), the MAX1864 generates three positive outputs, and the MAX1865 generates four positive outputs and one negative output to provide a cost-effective system power supply. The MAX1864 includes a current-mode synchronous step-down controller and two positive regulator gain blocks. The MAX1865 has one additional positive gain block and one negative regulator gain block. The main synchronous step-down controller generates a high-current output that is preset to 3.3 V or adjustable from 1.236 V to $0.8 \times \mathrm{V}$ IN with an external resistivedivider. The $100 \mathrm{kHz} / 200 \mathrm{kHz}$ operating frequency allows the use of low-cost aluminum-electrolytic capacitors and low-cost power magnetics. Additionally, the MAX1864/MAX1865 step-down controllers sense the voltage across the low-side MOSFET's on-resistance to efficiently provide the current-limit signal, eliminating the need for costly current-sense resistors. The MAX1864/MAX1865 generate additional supply rails at low cost. The positive regulator gain blocks use an external PNP pass transistor to generate low-voltage rails directly from the main step-down converter (such as 2.5 V or 1.8 V from the main 3.3 V output) or higher voltages using coupled windings from the step-down converter (such as 5V, 12V, or 15V). The MAX1865's negative gain block uses an external NPN pass transistor in conjunction with a coupled winding to generate $-5 \mathrm{~V},-12 \mathrm{~V}$, or -15 V . All output voltages are externally adjustable, providing maximum flexibility. Additionally, the MAX1864/ MAX1865 feature soft-start for the step-down converter and all the positive linear regulators, and have a powergood output that monitors all of the output voltages.


## Applications

xDSL, Cable, and ISDN Modems
Set-Top Boxes
Wireless Local Loop

Features
-4.5V to 28 V Input Voltage Range

- Master DC-DC Step-Down Converter

Preset 3.3 V or Adjustable ( 1.236 V to $0.8 \times \mathrm{V}$ IN ) Output Voltage
Fixed-Frequency ( $100 \mathrm{kHz} / 200 \mathrm{kHz}$ ) PWM
Controller
No Current-Sense Resistor
Adjustable Current Limit
95\% Efficient

- Two (MAX1864)/Four (MAX1865) Analog Gain Blocks

Positive Analog Blocks Drive Low-Cost PNP Pass Transistors to Build Positive Linear Regulators
Negative Analog Block (MAX1865) Drives a Low-Cost NPN Pass Transistor to Build a Negative Linear Regulator

- Power-Good Indicator
- Soft-Start Ramp for All Positive Regulators

Ordering Information

| PART | TEMP. <br> RANGE | PIN- <br> PACKAGE | fosc <br> (kHz) |
| :---: | :---: | :--- | :---: |
| MAX1864TEEE | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16 QSOP | 200 |
| MAX1864UEEE | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16 QSOP | 100 |
| MAX1865TEEP | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 20 QSOP | 200 |
| MAX1865UEEP | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 20 QSOP | 100 |

Pin Configurations


Pin Configurations continued at end of data sheet.

## xDSL/Cable Modem Triple/Quintuple Output Power Supplies

## ABSOLUTE MAXIMUM RATINGS

| IN, B2, B3, B4 to GND | -0.3 V to +30 V |
| :---: | :---: |
| B5 to OUT | -20V to +0.3V |
| VL, POK, FB, FB2, FB3, FB4, | .............-0.3V to +6V |
| LX to BST. | -6V to +0.3 V |
| BST to GND | -0.3V to +36V |
| DH to LX. | .-0.3V to (VBST + 0.3V) |
| DL, OUT, COMP, ILIM to GND | -0.3V to (VL+0.3V) |
| VL Output Current. | . 50 mA |
| L Short Circuit to GND | $\leq 100 \mathrm{~ms}$ |

Continuous Power Dissipation ( $\mathrm{T}_{\mathrm{A}}=+70^{\circ} \mathrm{C}$ )
16-Pin QSOP (derate $8.3 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ )........... 666 mW
20-Pin QSOP (derate $9.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ )........... 727 mW Operating Temperature Range ........................ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Junction Temperature ..................................................... $+150^{\circ} \mathrm{C}$
Storage Temperature Range ............................. $65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Lead Temperature (soldering, 10s) ................................. $+300^{\circ} \mathrm{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

$\left(V_{I N}=12 \mathrm{~V}, I L I M=F B=G N D, V_{B S T}-V_{L X}=5 \mathrm{~V}, \mathbf{T}_{\mathbf{A}}=\mathbf{0}^{\circ} \mathbf{C}\right.$ to $+\mathbf{8 5}{ }^{\circ} \mathbf{C}$. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| GENERAL |  |  |  |  |  |  |  |
| Operating Input Voltage Range (Note 1) | VIN |  |  | 4.5 |  | 28 | V |
| Quiescent Supply Current | IIN | $\begin{aligned} & V_{F B}=0, V_{\text {OUT }}=4 V, \\ & V_{F B 2}=V_{F B 3}=V_{F B 4}=1.5 \mathrm{~V}, \\ & V_{F B 5}=-0.1 V \end{aligned}$ | MAX1864 |  | 1.0 | 2 | mA |
|  |  |  | MAX1865 |  | 1.4 | 3 |  |
| VL REGULATOR |  |  |  |  |  |  |  |
| Output Voltage | VL | $6 \mathrm{~V}<\mathrm{V}_{\text {IN }}<28 \mathrm{~V}, 0.1 \mathrm{~mA}$ < ILOAD $<20 \mathrm{~mA}$ |  | 4.75 | 5.00 | 5.25 | V |
| Power-Supply Rejection | PSRR | $\mathrm{V}_{\mathrm{IN}}=6 \mathrm{~V}$ to 28V |  |  |  | 3 | \% |
| Undervoltage Lockout Trip Level | VUVLO | VL rising, 3\% hysteresis (typ) |  | 3.2 | 3.5 | 3.8 | V |
| Minimum Bypass Capacitance | CBYP(MIN) | $10 \mathrm{~m} \Omega<\mathrm{ESR}<500 \mathrm{~m} \Omega$ |  |  | 1 |  | $\mu \mathrm{F}$ |
| DC-DC CONTROLLER |  |  |  |  |  |  |  |
| Output Voltage (Preset Mode) | Vout | FB = GND |  | 3.272 | 3.314 | 3.355 | V |
| Typical Output Voltage Range (Adjustable Mode) (Note 2) | Vout |  |  | 1.236 |  | $0.8 \times \mathrm{V}$ IN | V |
| FB Set Voltage (Adjustable Mode) | VSET | $\mathrm{FB}=\mathrm{COMP}$ |  | 1.221 | 1.236 | 1.252 | V |
| FB Dual Mode ${ }^{\text {TM }}$ Threshold |  |  |  | 50 | 100 | 150 | mV |
| FB Input Leakage Current | IFB | $\mathrm{V}_{\mathrm{FB}}=1.5 \mathrm{~V}$ |  |  | 0.01 | 100 | nA |
| FB to COMP Transconductance | gm | FB $=$ COMP, $\mathrm{ICOMP}= \pm 5 \mu \mathrm{~A}$ |  | 70 | 100 | 140 | $\mu \mathrm{S}$ |
| Current-Sense Amplifier Voltage Gain | ALIM | VIN - $\mathrm{V}_{\text {LX }}=250 \mathrm{mV}$ |  | 4.46 | 4.9 | 5.44 | V/V |
| Current-Limit Threshold (Internal Mode) | VVaLLeY | $\mathrm{V}_{\text {ILIM }}=5.0 \mathrm{~V}$ |  | 190 | 250 | 310 | mV |
| Current-Limit Threshold (External Mode) | VVALLEY | V ILIM $=2.5 \mathrm{~V}$ |  | 440 | 530 | 620 | mV |

Dual Mode is a trademark of Maxim Integrated Products, Inc.

# xDSL/Cable Modem Triple/Quintuple Output Power Supplies 

## ELECTRICAL CHARACTERISTICS (continued)

$\left(V_{I N}=12 \mathrm{~V}, I L I M=F B=G N D, V_{B S T}-V_{L X}=5 \mathrm{~V}, \mathbf{T}_{\mathbf{A}}=\mathbf{0}^{\circ} \mathbf{C}\right.$ to $+\mathbf{8 5} \mathbf{5}^{\circ} \mathbf{C}$. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted. $)$

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Switching Frequency | fosc | MAX186_T | 160 | 200 | 240 | kHz |
|  |  | MAX186_U | 80 | 100 | 120 |  |
| Maximum Duty Cycle | DMAX |  | 77 | 82 | 90 | \% |
| Soft-Start Period | tSOFT |  |  | 1024 |  | 1/fosc |
| Soft-Start Steps |  |  |  | $\mathrm{V}_{\text {REF } / 64}$ |  | V |
| DH Output Low Voltage |  | ISINK $=10 \mathrm{~mA}$, measured from DH to LX |  |  | 0.1 | V |
| DH Output High Voltage |  | ISOURCE $=10 \mathrm{~mA}$, measured from BST to DH | 0.1 |  |  | V |
| DL Output Low Voltage |  | ISINK $=10 \mathrm{~mA}$, measured from DL to GND |  |  | 0.1 | V |
| DL Output High Voltage |  | ISOURCE $=10 \mathrm{~mA}$, measured from DL to GND | $\mathrm{V}_{\mathrm{L}}-0.1$ |  |  | V |
| DH, DL On-Resistance |  |  |  | 3 | 10 | $\Omega$ |
| Output Drive Current |  | Sourcing or sinking, $\mathrm{V}_{\mathrm{DH}}$ or $\mathrm{V}_{\mathrm{DL}}=\mathrm{VL} / 2$ |  | 0.5 |  | A |
| LX, BST Leakage Current |  | $\mathrm{V}_{\mathrm{BST}}=\mathrm{V}_{\mathrm{LX}}=\mathrm{V}_{\mathrm{IN}}=28 \mathrm{~V}, \mathrm{~V}_{\mathrm{FB}}=1.5 \mathrm{~V}$ |  | 0.03 | 20 | $\mu \mathrm{A}$ |


| FB2, FB3, FB4 Regulation Voltage |  | $\begin{aligned} & V_{\mathrm{B} 2}=\mathrm{V}_{\mathrm{B} 3}=\mathrm{V}_{\mathrm{B} 4}=5 \mathrm{~V}, \\ & I_{\mathrm{B} 2}=I_{\mathrm{B} 3}=I_{\mathrm{B} 4}=1 \mathrm{~mA} \text { (sink) } \end{aligned}$ |  | 1.226 | 1.240 | 1.257 | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| FB2, FB3, FB4 to B_ Transconductance | $\Delta V_{\text {FB_ }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{B} 2}=\mathrm{V}_{\mathrm{B} 3}=\mathrm{V}_{\mathrm{B} 4}=5 \mathrm{~V} \text {, } \mathrm{I}_{\mathrm{B} 2}=\mathrm{I}_{\mathrm{B} 3}=\mathrm{I}_{\mathrm{B} 4}= \\ & 0.5 \mathrm{~mA} \text { to } 5 \mathrm{~mA} \text { (sink) } \end{aligned}$ |  |  | -1 | -1.75 | \% |
| Feedback Input Leakage Current | IfB_ | $\mathrm{V}_{\mathrm{FB} 2}=\mathrm{V}_{\mathrm{FB} 3}=\mathrm{V}_{\mathrm{FB} 4}=1.5 \mathrm{~V}$ |  |  | 0.01 | 100 | nA |
| Driver Sink Current | $\mathrm{I}_{\mathrm{B}}$ | $\begin{aligned} & V_{F B 2}=V_{F B 3}= \\ & V_{F B 4}=1.188 \mathrm{~V} \end{aligned}$ | $\mathrm{V}_{\mathrm{B} 2}=\mathrm{V}_{\mathrm{B} 3}=\mathrm{V}_{\mathrm{B} 4}=2.5 \mathrm{~V}$ | 10 | 23 |  | mA |
|  |  |  | $\mathrm{V}_{\mathrm{B} 2}=\mathrm{V}_{\mathrm{B} 3}=\mathrm{V}_{\mathrm{B} 4}=4.0 \mathrm{~V}$ |  | 26 |  |  |

NEGATIVE ANALOG GAIN BLOCK

| FB5 Regulation Voltage |  | $\mathrm{V}_{\mathrm{B} 5}=\mathrm{V}_{\text {OUT }}-2 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{B} 5}=1 \mathrm{~mA}$ (source) | -20 | -5 | +10 | mV |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| FB5 to B5 Transconductance | $\Delta \mathrm{V}_{\text {FB5 }}$ | $\mathrm{V}_{\mathrm{B} 5}=0, \mathrm{I}_{\mathrm{B} 5}=0.5 \mathrm{~mA}$ to 5 mA (source) |  | -13 | -20 | mV |
| Feedback Input Leakage Current | IfB5 | $\mathrm{V}_{\text {FB5 }}=-100 \mathrm{mV}$ |  | 0.01 | 100 | nA |
| Driver Source Current | IB5 | $\begin{aligned} & V_{\text {FB5 }}=200 \mathrm{mV}, V_{\text {B5 }}=V_{\text {OUT }}-2.0 \mathrm{~V}, \text { VOUT }= \\ & 3.5 \mathrm{~V} \end{aligned}$ | 10 | 25 |  | mA |
| POWER GOOD (POK) |  |  |  |  |  |  |
| OUT Trip Level (Preset Mode) |  | FB = GND, falling edge, 1\% hysteresis (typ) | 2.88 | 3 | 3.12 | V |
| FB Trip Level (Adjustable Mode) |  | Falling edge, 1\% hysteresis (typ) | 1.070 | 1.114 | 1.159 | V |
| FB2, FB3, FB4 Trip Level |  | Falling edge, 1\% hysteresis (typ) | 1.070 | 1.114 | 1.159 | V |
| FB5 Trip Level |  | Rising edge, 35mV hysteresis (typ) | 368 | 500 | 632 | mV |
| POK Output Low Level |  | $\mathrm{ISINK}=1 \mathrm{~mA}$ |  |  | 0.4 | V |
| POK Output High Leakage |  | $\mathrm{V}_{\mathrm{POK}}=5 \mathrm{~V}$ |  |  | 1 | $\mu \mathrm{A}$ |
| THERMAL PROTECTION (Note 3) |  |  |  |  |  |  |
| Thermal Shutdown |  | Rising temperature |  | 160 |  | ${ }^{\circ} \mathrm{C}$ |
| Thermal Shutdown Hysteresis |  |  |  | 15 |  | ${ }^{\circ} \mathrm{C}$ |

## xDSL/Cable Modem Triple/Quintuple Output Power Supplies

ELECTRICAL CHARACTERISTICS
$\left(\mathrm{V}_{I N}=12 \mathrm{~V}, \mathrm{ILIM}=\mathrm{FB}=\mathrm{GND}, \mathrm{V}_{\mathrm{BST}}-\mathrm{V}_{\mathrm{LX}}=5 \mathrm{~V}, \mathbf{T}_{\mathbf{A}}=\mathbf{- 4 0 ^ { \circ }} \mathbf{C}\right.$ to $+\mathbf{8 5} 5^{\circ} \mathrm{C}$, unless otherwise noted. $)$ (Note 4)

| PARAMETER | SYMBOL | CONDITIONS |  | MIN | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| GENERAL |  |  |  |  |  |  |
| Operating Input Voltage Range (Note 1) | VIN |  |  | 4.5 | 28 | V |
| Quiescent Supply Current | IIN | $\begin{aligned} & V_{F B}=0, V_{O U T}=4 V, V_{F B 2} \\ & =V_{F B 3}=V_{F B 4}=1.5 \mathrm{~V}, \\ & V_{F B 5}=-0.1 \mathrm{~V} \end{aligned}$ | MAX1864 |  | 2 | mA |
|  |  |  | MAX1865 |  | 3 |  |
| VL REGULATOR |  |  |  |  |  |  |
| Output Voltage | VL | $6 \mathrm{~V}<\mathrm{V}_{\text {IN }}<28 \mathrm{~V}, 0.1 \mathrm{~mA}$ < ILOAD $<20 \mathrm{~mA}$ |  | 4.75 | 5.25 | V |
| Power-Supply Rejection | PSRR | V IN $=6 \mathrm{~V}$ to 28 V |  |  | 3 | \% |
| Undervoltage Lockout Trip Level | VUVLO | VL rising, 3\% hysteresis (typ) |  | 3 | 4 | V |
| DC-DC CONTROLLER |  |  |  |  |  |  |
| Output Voltage (Preset Mode) | Vout | $\mathrm{FB}=\mathrm{GND}$ |  | 3.247 | 3.380 | V |
| Feedback Set Voltage (Adjustable Mode) | $V_{\text {SET }}$ | $\mathrm{FB}=\mathrm{COMP}$ |  | 1.211 | 1.261 | V |
| Current-Sense Amplifier Voltage Gain | ALIM | $\mathrm{V}_{\mathrm{IN}}-\mathrm{V}_{\text {LX }}=250 \mathrm{mV}$ |  | 4.12 | 5.68 | V/V |
| Current-Limit Threshold (Internal Mode) | VVaLLEY | $\mathrm{V}_{\text {ILIM }}=5 \mathrm{~V}$ |  | 150 | 350 | mV |
| Current-Limit Threshold (External Mode) | VVALLEY | $\mathrm{V}_{\text {ILIM }}=2.5 \mathrm{~V}$ |  | 400 | 660 | mV |
| Switching Frequency | fosc | MAX186_T |  | 160 | 240 | kHz |
|  |  | MAX186_U |  | 80 | 120 |  |
| Maximum Duty Cycle | DMAX |  |  | 74 | 90 | \% |
| POSITIVE ANALOG GAIN BLOCKS |  |  |  |  |  |  |
| FB2, FB3, FB4 Regulation Voltage |  | $\begin{aligned} & \mathrm{V}_{\mathrm{B} 2}=\mathrm{V}_{\mathrm{B} 3}=\mathrm{V}_{\mathrm{B} 4}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{B} 2}=\mathrm{I}_{\mathrm{B} 3}=\mathrm{I}_{\mathrm{B} 4}= \\ & 1 \mathrm{~mA} \text { (sink) } \end{aligned}$ |  | 1.215 | 1.265 | V |
| FB2, FB3, FB4 to B_ <br> Transconductance | $\Delta \mathrm{V}_{\mathrm{FB}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{B} 2}=\mathrm{V}_{\mathrm{B} 3}=\mathrm{V}_{\mathrm{B} 4}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{B} 2}=\mathrm{I}_{\mathrm{B} 3}=\mathrm{I}_{\mathrm{B} 4}= \\ & 0.5 \mathrm{~mA} \text { to } 5 \mathrm{~mA} \text { (sink) } \end{aligned}$ |  |  | -2.25 | \% |
| NEGATIVE ANALOG GAIN BLOCK |  |  |  |  |  |  |
| FB5 Regulation Voltage |  | $\mathrm{V}_{\mathrm{B} 5}=\mathrm{V}_{\text {OUT }}-2 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{B} 5}=1 \mathrm{~mA}$ (source) |  | -25 | +10 | mV |
| FB5 to B5 Transconductance | $\Delta V_{\text {FB5 }}$ | $\mathrm{V}_{\mathrm{B} 5}=0, \mathrm{I}_{\mathrm{B} 5}=0.5 \mathrm{~mA}$ to 5 mA (source) |  |  | -30 | mV |

# xDSL/Cable Modem Triple/Quintuple Output Power Supplies 

## ELECTRICAL CHARACTERISTICS (continued)

$\left(V_{I N}=12 \mathrm{~V}, \mathrm{ILIM}=\mathrm{FB}=\mathrm{GND}, \mathrm{V}_{\mathrm{BST}}-\mathrm{V}_{\mathrm{LX}}=5 \mathrm{~V}, \mathbf{T}_{\mathbf{A}}=\mathbf{- 4 0 ^ { \circ }} \mathbf{C}\right.$ to $+\mathbf{8 5} 5^{\circ} \mathrm{C}$, unless otherwise noted. $)($ Note 4)

| PARAMETER |  | SYMBOL | CONDITIONS | MIN | MAX |  | UNITS |  |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| POWER GOOD (POK) |  |  |  |  |  |  |  | FB = GND, falling edge, 1\% hysteresis (typ) | 2.85 | 3.15 | V |
| OUT Trip Level (Preset Mode) |  | Falling edge, 1\% hysteresis (typ) | 1.058 | 1.17 | V |  |  |  |  |  |  |
| FB Trip Level <br> (Adjustable Mode) |  | Falling edge, 1\% hysteresis (typ) | 1.058 | 1.17 | V |  |  |  |  |  |  |
| FB2, FB3, FB4 Trip Level |  | Rising edge, 35mV hysteresis (typ) | 325 | 675 | mV |  |  |  |  |  |  |
| FB5 Trip Level |  |  |  |  |  |  |  |  |  |  |  |

Note 1: Connect VL to IN for operation with $\mathrm{V}_{\mathrm{IN}}<5 \mathrm{~V}$.
Note 2: See Output Voltage Selection section.
Note 3: The internal 5 V linear regulator (VL) powers the thermal shutdown block. Shorting VL to GND disables thermal shutdown.
Note 4: Specifications to $-40^{\circ} \mathrm{C}$ are guaranteed by design, not production tested.

## Typical Operating Characteristics

(Circuit of Figure 1, $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


## xDSL/Cable Modem Triple/Quintuple Output Power Supplies

(Circuit of Figure 1, $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)

A. VOUT $=3.3 \mathrm{~V}$ (PRESET), $200 \mathrm{mV} / \mathrm{div}$
B. IOUT $=10 \mathrm{~mA}$ TO $1 \mathrm{~A}, 500 \mathrm{~mA} /$ div
$\mathrm{V}_{\mathbb{I}}=12 \mathrm{~V}$

A. $\mathrm{V}_{\mathrm{L}}, 5 \mathrm{~V} / \mathrm{div}$
B. $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}$ (PRESET), $2 \mathrm{~V} / \mathrm{div}$
$\mathrm{V}_{\mathrm{IN}}=0$ TO 12 V

POSITIVE LINEAR REGULATOR BASEDRIVE CURRENT vs. BASE-DRIVE VOLTAGE


# xDSL/Cable Modem Triple/Quintuple Output Power Supplies 

Typical Operating Characteristics (continued)
(Circuit of Figure 1, $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}$, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


POSITIVE LINEAR REGULATOR OUTPUT VOLTAGE vs. SUPPLY VOLTAGE
( $Q_{\text {ldo }}=2 \mathrm{~N} 3905$ )


POSITIVE LINEAR REGUALTOR OUTPUT VOLTAGE vs. LOAD CURRENT (Qlod = TIP30)


POSITIVE LINEAR REGULATOR POWER-SUPPLY REJECTION RATIO ( $Q_{\text {ldo }}=2 N 3905$ )


POSITIVE LINEAR REGULATOR OUTPUT VOLTAGE vs. SUPPLY VOLTAGE

A. $I_{\text {OUTZ }}=1 \mathrm{~mA}$ TO $100 \mathrm{~mA}, 50 \mathrm{~mA} / \mathrm{div}$
B. $\mathrm{V}_{\text {Outz }}=2.5 \mathrm{~V}, 5 \mathrm{mV} / \mathrm{div}$
$C_{\text {LDO(POS })}=10 \mu \mathrm{~F}$ CERAMIC, $\mathrm{V}_{\text {SUP }}(P O S)=3.3 \mathrm{~V}$ CIRCUIT OF FIGURE 1

## xDSL/Cable Modem Triple/Quintuple Output Power Supplies

Typical Operating Characteristics (continued)
(Circuit of Figure 1, $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


NEGATIVE LINEAR REGULATOR OUTPUT VOLTAGE vs. LOAD CURRENT
(Qldo = TIP29)


NEGATIVE LINEAR REGULATOR OUTPUT VOLTAGE vs. SUPPLY VOLTAGE
( $\mathbf{C L D O}=$ TIP29)


# xDSL/Cable Modem Triple/Quintuple Output Power Supplies 

Pin Description

| PIN |  | NAME | FUNCTION |
| :---: | :---: | :---: | :---: |
| MAX1864 | MAX1865 |  |  |
| 1 | 1 | POK | Open-Drain Power-Good Output. POK is low when the output voltage is more than $10 \%$ below the regulation point. POK is high impedance when the output is in regulation. Connect a resistor between POK and VL for logic-level voltages. |
| 2 | 2 | COMP | Compensation Pin. Connect a series RC to GND to compensate the control loop. Typical values are $47 \mathrm{k} \Omega$ and 8.2 nF . |
| 3 | 3 | OUT | Regulated Output Voltage High-Impedance Sense Input. Internally connected to a resistive-divider and negative gain block (MAX1865). |
| 4 | 4 | FB | Dual Mode Switching-Regulator Feedback Input. Connect to GND for the preset 3.3V output. Connect to a resistive-divider from output to FB to GND to adjust the output voltage between 1.236 V and $0.8 \times \mathrm{V}$ IN . The feedback set point is 1.236 V . |
| 5 | 5 | B2 | Open-Drain Output PNP Transistor Driver (Regulator \#2). Internally connected to the drain of a DMOS. B2 connects to the base of an external PNP pass transistor to form a positive linear regulator. |
| 6 | 6 | FB2 | Analog Gain-Block Feedback Input (Regulator \#2). Connect to a resistive-divider between the positive linear regulator's output and GND to adjust the output voltage. The feedback set point is 1.24 V . |
| 7 | 7 | B3 | Open-Drain Output PNP Transistor Driver (Regulator \#3). Internally connected to the drain of a DMOS. B3 connects to the base of an external PNP pass transistor to form a positive linear regulator. |
| 8 | 8 | FB3 | Analog Gain-Block Feedback Input (Regulator \#3). Connect to a resistive-divider between the positive linear regulator's output and GND to adjust the output voltage. The feedback set point is 1.24 V . |
| - | 9 | B4 | Open-Drain Output PNP Transistor Driver (Regulator \#4). Internally connected to the drain of a DMOS. B4 connects to the base of an external PNP pass transistor to form a positive linear regulator. |
| - | 10 | FB4 | Analog Gain-Block Feedback Input (Regulator \#4). Connect to a resistive-divider between the positive linear regulator's output and GND to adjust the output voltage. The feedback set point is 1.24 V . |
| - | 11 | B5 | Open-Drain Output NPN Transistor Driver (Regulator \#5). Internally connected to the drain of a P-channel MOSFET. B5 connects to the base of an external NPN pass transistor to form a negative linear regulator. |
| - | 12 | FB5 | Analog Gain-Block Feedback Input (Regulator \#5). Connect to a resistive-divider between the negative linear regulator's output and a positive reference voltage, typically one of the positive linear regulator outputs, to adjust the output voltage. The feedback set point is at GND. |

# xDSL/Cable Modem Triple/Quintuple Output Power Supplies 

Pin Description (continued)

| PIN |  | NAME | FUNCTION |
| :---: | :---: | :---: | :---: |
| MAX1864 | MAX1865 |  |  |
| 9 | 13 | ILIM | Dual Mode Current-Limit Adjustment Input. Connect to VL for the default 250 mV current-limit threshold. In adjustable mode, the current-limit threshold voltage is $1 / 5$ th the voltage present at ILIM. Connect to a resistive-divider between VL and GND to adjust VIIIM between 1 V and 2.5 V . The logic threshold for switchover to the 250 mV default value is approximately VL-1V. |
| 10 | 14 | GND | Ground |
| 11 | 15 | DL | Low-Side Gate-Driver Output. DL swings between GND and VL. |
| 12 | 16 | LX | Inductor Connection. Used for current sense between IN and LX, and used for current limit between LX and GND. |
| 13 | 17 | DH | High-Side Gate-Driver Output. DH swings between LX and BST. |
| 14 | 18 | BST | Boost Flying Capacitor Connection. Connect BST to the external boost diode and capacitor as shown in the standard application circuit (Figures 1 and 6). |
| 15 | 19 | VL | Internal 5V Linear-Regulator Output. Supplies the IC and powers the DL low-side gate driver and external boost diode and capacitor. Bypass with a $1 \mu \mathrm{~F}$ or greater ceramic capacitor to GND. |
| 16 | 20 | IN | Input Supply Voltage, 4.5 V to 28 V . Bypass to GND with a $1 \mu \mathrm{~F}$ or greater ceramic capacitor close to the IC. |

## Detailed Description

The MAX1864/MAX1865 power-supply controllers provide system power for cable and xDSL modems. The main step-down DC-DC controller operates in a cur-rent-mode pulse-width-modulation (PWM) control scheme to ease compensation requirements and provide excellent load- and line-transient response.
The MAX1864 includes two analog gain blocks to regulate two additional positive auxiliary output voltages, and the MAX1865 includes four analog gain blocks to regulate three additional positive and one negative auxiliary output voltages. The positive regulator gain blocks can be used to generate low-voltage rails directly from the main step-down converter or higher voltages using coupled windings from the step-down converter. The negative gain block can be used in conjunction with a coupled winding to generate $-5 \mathrm{~V},-12 \mathrm{~V}$, or -15 V .

## DC-DC Controller

The MAX1864/MAX1865 step-down converters use a pulse-width-modulated (PWM) current-mode control scheme (Figure 2). An internal transconductance amplifier establishes an integrated error voltage at the COMP pin. The heart of the current-mode PWM controller is an open-loop comparator that compares the
integrated voltage-feedback signal against the amplified current-sense signal plus the slope compensation ramp. At each rising edge of the internal clock, the high-side MOSFET turns-on until the PWM comparator trips or the maximum duty cycle is reached. During this on-time, current ramps up through the inductor, sourcing current to the output and storing energy in a magnetic field. The current-mode feedback system regulates the peak inductor current as a function of the output voltage error signal. Since the average inductor current is nearly the same as the peak inductor current (assuming that the inductor value is relatively high to minimize ripple current), the circuit acts as a switchmode transconductance amplifier. It pushes the output LC filter pole, normally found in a voltage-mode PWM, to a higher frequency. To preserve inner loop stability and eliminate inductor stair-casing, a slope-compensation ramp is summed into the main PWM comparator.
During the second-half of the cycle, the high-side MOSFET turns off and the low-side N-channel MOSFET turns on. Now the inductor releases the stored energy as its current ramps down, providing current to the output. Therefore, the output capacitor stores charge when the inductor current exceeds the load current and discharges when the inductor current is lower, smoothing

# xDSL/Cable Modem Triple/Quintuple Output Power Supplies 



Figure 1. Standard MAX1864 Application Circuit
the voltage across the load. Under overload conditions, when the inductor current exceeds the selected cur-rent-limit (see the Setting the Current Limit section), the high-side MOSFET is not turned on at the rising edge of the clock and the low-side MOSFET remains on to let the inductor current ramp down.
The MAX1864/MAX1865 operate in a forced-PWM mode, so even under light loads the controller maintains a constant switching frequency to minimize crossregulation errors in applications that use a transformer. The low-side gate-drive waveform is the complement of the high-side gate-drive waveform, which causes the inductor current to reverse under light loads.

## Current-Sense Amplifier

The MAX1864/MAX1865s' current-sense circuit amplifies $(A v=5)$ the current-sense voltage generated by the high-side MOSFET's on-resistance (RDS(ON) $\times$ IINDUCTOR). This amplified current-sense signal and the internal slope compensation signal are summed together (VSUM) and fed into the PWM comparator's inverting input. The PWM comparator turns-off the highside MOSFET when VSUM exceeds the integrated feedback voltage (VCOMP). Place the high-side MOSFET no further than 5 mm from the controller, and connect IN and LX to the MOSFET using Kelvin sense connections to guarantee current-sense accuracy and improve stability.

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MAX1864/MAX1865


Figure 2. Functional Diagram

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## Current-Limit Circuit

 The current-limit circuit employs a unique "valley" cur-rent-limiting algorithm that uses the low-side MOSFET's on-resistance as a sensing element (Figure 3). If the voltage across the low-side MOSFET (RDS(ON) $\times$ IINDUCTOR) exceeds the current-limit threshold at the beginning of a new oscillator cycle, the MAX1864/ MAX1865 will not turn on the high-side MOSFET. The actual peak current is greater than the current-limit threshold by an amount equal to the inductor ripple current. Therefore, the exact current-limit characteristic and maximum load capability are a function of the lowside MOSFET on-resistance, inductor value, input voltage, and output voltage. The reward for this uncertainty is robust, loss-less overcurrent limiting.In adjustable mode, the current-limit threshold voltage is $1 / 5$ th the voltage seen at ILIM (IVALLEY $=0.2 \times \mathrm{V}_{\text {ILIIM }}$ ). Adjust the current-limit threshold by connecting a resis-tive-divider from VL to ILIM to GND. The current-limit threshold can be set from 106 mV to 530 mV , which corresponds to ILIM input voltages of 500 mV to 2.5 V . This adjustable current limit accommodates MOSFETs with a wide range of on-resistance characteristics (see Design Procedure). The current-limit threshold defaults to 250 mV when ILIM is connected to VL. The logic threshold for switchover to the 250 mV default value is approximately VL-1V.
Carefully observe the PC board layout guidelines to ensure that noise and DC errors don't corrupt the cur-rent-sense signals seen by LX and GND. The IC must be mounted close to the low-side MOSFET with short (less than 5 mm ), direct traces making a Kelvin sense connection.

Synchronous Rectifier Driver (DL) Synchronous rectification reduces conduction losses in the rectifier by replacing the normal Schottky catch diode with a low-resistance MOSFET switch. The MAX1864/MAX1865 also use the synchronous rectifier to ensure proper startup of the boost gate-driver circuit and to provide the current-limit signal.
The DL low-side drive waveform is always the complement of the DH high-side drive waveform (with controlled dead time to prevent cross-conduction or "shoot-through"). A dead-time circuit monitors the DL output and prevents the high-side FET from turning on until DL is fully off. For the dead-time circuit to work properly, there must be a low-resistance, low-inductance path from the DL driver to the MOSFET gate. Otherwise, the sense circuitry in the MAX1864/ MAX1865 will interpret the MOSFET gate as "off" when gate charge actually remains. Use very short, wide


Figure 3. "Valley" Current-Limit Threshold Point
traces ( 50 mil to 100 mil wide if the MOSFET is 1 inch from the device). The dead time at the other edge (DH turning off) is determined by a fixed internal delay.

High-Side Gate-Drive Supply (BST) Gate-drive voltage for the high-side N -channel switch is generated by a flying-capacitor boost circuit (Figure 1). The capacitor between BST and LX is alternately charged from the VL supply and placed parallel to the high-side MOSFET's gate-source terminals.
On startup, the synchronous rectifier (low-side MOSFET) forces LX to ground and charges the boost capacitor to 5 V . On the second half-cycle, the switchmode power supply turns on the high-side MOSFET by closing an internal switch between BST and DH. This provides the necessary gate-to-source voltage to turn on the high-side switch, an action that boosts the 5 V gate-drive signal above the battery voltage.

## Internal 5V Linear Regulator (VL)

All MAX1864/MAX1865 functions, except the currentsense amplifier, are internally powered from the onchip, low-dropout 5 V regulator. The maximum regulator input voltage $(\mathrm{V} / \mathrm{N})$ is 28 V . Bypass the regulator's output (VL) with at least a $1 \mu \mathrm{~F}$ ceramic capacitor to GND. The VIN-to-VL dropout voltage is typically 200 mV , so when VIN is less than 5.2 V , VL is typically $\mathrm{VIN}-200 \mathrm{mV}$.
The internal linear regulator can source up to 20 mA to supply the IC, power the low-side gate driver, charge the external boost capacitor, and supply small external loads. When driving particularly large FETs, little or no regulator current may be available for external loads. For example, when switched at 200 kHz , a large FET with 40 nC total gate charge requires $40 \mathrm{nC} \times 200 \mathrm{kHz}$, or 8 mA .

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## Undervoltage Lockout

If VL drops below 3.5V, the MAX1864/MAX1865 assume that the supply voltage is too low to make valid decisions, so the undervoltage lockout (UVLO) circuitry inhibits switching, forces POK low, and forces the DL and DH gate drivers low. After VL rises above 3.5 V , internal digital soft-start is initiated (see Soft-Start).

## Startup Sequence

Externally, the MAX1864/MAX1865 starts switching when VL rises above the 3.5 V undervoltage lockout threshold. However, the controller is not enabled unless all four of the following conditions are met: 1) VL exceeds the 3.5 V undervoltage lockout threshold, 2) the internal reference exceeds $90 \%$ of its nominal value (VREF > 1.114 V ), 3) the internal bias circuitry powers up, and 4) the thermal limit is not exceeded. Once the MAX1864/MAX1865 assert the internal enable signal, the step-down controller starts switching and enables soft-start.

Soft-Start
Upon power-up, the MAX1864/MAX1865 begin a startup sequence. First, the reference powers up. Then, the main DC-DC step-down converter and positive linear regulators power up with soft-start enabled. Once the regulators reach $90 \%$ of their nominal value and softstart is complete, the active-high ready signal (POK) goes high (see Power-Good Output).
Soft-start gradually ramps up to the reference voltage in order to control the rate of rise of the output voltages and reduce input surge currents during startup. The soft-start period is 1024 clock cycles (1024/fosc), and the internal soft-start DAC ramps up the voltage in 64 steps. The output reaches regulation when soft-start is completed, regardless of output capacitance and load.

Power-Good Output
The power-good output (POK) is an open-drain output. The MOSFET turns on and pulls POK low when any output is less than $90 \%$ of its nominal regulation voltage or during soft-start. Once all of the outputs exceed $90 \%$ of their nominal regulation voltages and soft-start is completed, POK goes high impedance. To obtain a logic voltage output, connect a pullup resistor from POK to VL. A $100 \mathrm{k} \Omega$ resistor works well for most applications. If unused, leave POK grounded or unconnected.

## Thermal-Overload Protection

Thermal-overload protection limits total power dissipation in the MAX1864/MAX1865. When the junction temperature exceeds $\mathrm{TJ}=+160^{\circ} \mathrm{C}$, a thermal sensor shuts down the device, forcing DL and DH low, allowing the IC to cool. The thermal sensor turns the part on again after the junction temperature cools by $10^{\circ} \mathrm{C}$, resulting in a pulsed output during continuous thermal-overload conditions. If the VL output is short circuited, thermaloverload protection is disabled.
During a thermal event, the main step-down converter and the linear regulators are turned off, POK goes low, and soft-start is reset.

## Design Procedure

## DC-DC Step-Down Converter Output Voltage Selection

The step-down controller's feedback input features Dual Mode operation. Connect the output to OUT and connect FB to GND for the preset 3.3 V output voltage. Alternatively, the MAX1864/MAX1865 output voltage may be adjusted by connecting a voltage-divider from the output to FB to GND (Figure 4). Select R2 in the $5 \mathrm{k} \Omega$ to $50 \mathrm{k} \Omega$ range. Calculate R1 with the following equation:

$$
\mathrm{R} 1=\mathrm{R} 2\left[\left(\frac{V_{\text {OUT }}}{V_{\text {SET }}}\right)-1\right]
$$

where $\mathrm{V}_{\text {SET }}=1.236 \mathrm{~V}$, and $\mathrm{V}_{\text {OUT }}$ may range from 1.236 V to approximately $0.8 \times \mathrm{V}_{\mathrm{IN}}$ (up to 20 V ). If Vout $>5.5 \mathrm{~V}$, then connect OUT to GND (MAX1864) or to one of the positive linear regulators (MAX1865) with an output voltage between 2 V and 5 V .

## Inductor Value

Three key inductor parameters must be specified: inductance value (L), peak current (IPEAK), and DC resistance ( $\mathrm{RDC}_{\mathrm{D}}$ ). The following equation includes a constant LIR, which is the ratio of inductor peak-topeak AC current to DC load current. A higher LIR value allows smaller inductance but results in higher losses and higher output ripple. A good compromise between size and losses is a $30 \%$ ripple-current to load-current ratio (LIR $=0.3$ ). The switching frequency, input voltage, output voltage, selected LIR determine the inductor value as follows:

$$
L=\frac{V_{\text {OUT }}\left(V_{\text {IN }}-V_{\text {OUT }}\right)}{V_{\text {IN }} f_{\text {SWW }} l_{\text {LOAD(MAX }} \text { LIR }}
$$

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Figure 4. Adjustable Output Voltage
where fsw is 200 kHz for MAX186_T and 100 kHz for MAX186_U. The exact inductor value is not critical and can be adjusted to make trade-offs among size, cost, and efficiency. Lower inductor values minimize size and cost, but they also increase the output ripple and reduce the efficiency due to higher peak currents. On the other hand, higher inductor values increase efficiency, but at some point resistive losses due to extra turns of wire will exceed the benefit gained from lower AC current levels.
Find a low-loss inductor having the lowest possible DC resistance that fits in the allotted dimensions. Ferrite cores are often the best choice, though powdered iron is inexpensive and can work well at 200 kHz . The chosen inductor's saturation rating must exceed the peak inductor current:

$$
I_{\text {PEAK }}=I_{\text {LOAD }}(\mathrm{MAX})+\left(\frac{\operatorname{LIR}}{2}\right) \operatorname{L}_{\operatorname{LOAD}(M A X)}
$$

Setting the Current Limit
The minimum current-limit threshold must be high enough to support the maximum load current at the minimum tolerance level of the current-limit circuit. The
valley of the inductor current occurs at ILOAD(MAX) minus half of the ripple current:

$$
\frac{V_{V A L L E Y(L O W)}}{\left.R_{D S(O N}\right)}>\operatorname{loAD(MAX)}-\left(\frac{\operatorname{LIR}}{2}\right) \operatorname{LOAD}(M A X)
$$

where $\mathrm{RDS}_{\mathrm{DS}}(\mathrm{ON})$ is the on-resistance of the low-side MOSFET ( $N_{L}$ ). For the MAX1864/MAX1865, the minimum current-limit threshold is 190 mV (for the typical 250 mV default setting). Use the worst-case maximum value for RDS(ON) from the MOSFET NL data sheet, and add some margin for the rise in $\operatorname{RDS}(\mathrm{ON})$ over temperature. A good general rule is to allow 0.5\% additional resistance for each ${ }^{\circ} \mathrm{C}$ of the MOSFET junction temperature rise.
Connect ILIM to VL for the default 250mV (typ) currentlimit threshold. For an adjustable threshold, connect a resistive-divider from VL to ILIM to GND. The 500 mV to 2.5 V external adjustment range corresponds to a 106 mV to 530 mV current-limit threshold. When adjusting the current limit, use $1 \%$ tolerance resistors and a $10 \mu \mathrm{~A}$ divider current to prevent a significant increase in the current-limit tolerance.

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## MOSFET Selection

The MAX1864/MAX1865s' step-down controller drives two external logic-level N -channel MOSFETs as the circuit switch elements. The key selection parameters are:

- On-resistance (RDS(ON))
- Maximum drain-to-source voltage (VDS(MAX))
- Minimum threshold voltage (VTH(MIN))
- Total gate charge $\left(\mathrm{Q}_{\mathrm{g}}\right)$
- Reverse transfer capacitance (CRSS)

The high-side N -channel MOSFET must be a logic-level type with guaranteed on-resistance specifications at $\mathrm{V}_{\mathrm{GS}} \leq 4.5 \mathrm{~V}$. Select the high-side MOSFET's RDS(ON) so IPEAK $\times \operatorname{RDS}(O N) \leq 225 \mathrm{mV}$ for the current-sense range. For maximum efficiency, choose a high-side MOSFET $\left(\mathrm{N}_{\mathrm{H}}\right)$ that has conduction losses equal to the switching losses at the optimum input voltage. Check to ensure that the conduction losses at minimum input voltage don't exceed the package thermal limits or violate the overall thermal budget. Check to ensure that the conduction losses plus switching losses at the maximum input voltage don't exceed package ratings or violate the overall thermal budget.
The low-side MOSFET ( NL ) provides the current-limit signal, so choose a MOSFET with an RDS(ON) large enough to provide adequate circuit protection (see Setting the Current Limit):

$$
\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}=\frac{\mathrm{V}_{\mathrm{VALLEY}}}{\mathrm{I}_{\mathrm{VALLEY}}}
$$

Use the worst-case maximum value for $\mathrm{RDS}(\mathrm{ON})$ from the MOSFET NL data sheet, and add some margin for the rise in $\operatorname{RDS}(O N)$ over temperature. A good general rule is to allow $0.5 \%$ additional resistance for each ${ }^{\circ} \mathrm{C}$ of the MOSFET junction temperature rise. Ensure that the MAX1864/MAX1865 DL gate drivers can drive NL; in other words, check that the dv/dt caused by NH turning on does not pull up the NL gate due to drain-to-gate capacitance, causing cross-conduction problems.
MOSFET package power dissipation often becomes a dominant design factor. I2R power losses are the greatest heat contributor for both high-side and low-side MOSFETs. I2R losses are distributed between NH and $N_{L}$ according to duty factor as shown in the equations below. Generally, switching losses affect only the highside MOSFET since the low-side MOSFET is a zero-voltage switched device when used in the buck topology.
Gate-charge losses are dissipated by the driver and do not heat the MOSFET. Calculate the temperature rise according to package thermal-resistance specifications
to ensure that both MOSFETs are within their maximum junction temperature at high ambient temperature. The worst-case dissipation for the high-side MOSFET (PNH) occurs at both extremes of input voltage, and the worst-case dissipation for the low-side MOSFET (PNL) occurs at maximum input voltage.

$$
\begin{aligned}
& \text { Duty Cycle: } \mathrm{D}=\frac{\mathrm{V}_{\mathrm{OUT}}}{\mathrm{~V}_{\mathrm{IN}}} \\
& \mathrm{P}_{\mathrm{NH}(\mathrm{SWITCHING})}=\mathrm{V}_{\text {INLOAD }} f_{\mathrm{OSC}}\left(\frac{\mathrm{~V}_{\text {IN }} \mathrm{C}_{\text {RSS }}}{I_{\text {GATE }}}\right) \\
& P_{\text {NH(CONDUCTION })}=\operatorname{loAD~}^{2} \mathrm{R}_{\mathrm{DS}(\mathrm{ON}) \mathrm{NH}} \mathrm{D}^{\mathrm{L}} \\
& P_{\text {NH(TOTAL) }}=P_{\text {NH(SWITCHING) }}+ \\
& P_{\text {NH(CONDUCTION }} \\
& P_{N L}=\operatorname{loAAD}^{2} \mathrm{R}_{\mathrm{DS}(\mathrm{ON}) \mathrm{NL}}(1-\mathrm{D})
\end{aligned}
$$

where IGATE is the DH driver peak output current capability ( 1 A typ), and 20 ns is the DH driver inherent rise/fall-time. To reduce EMI caused by switching noise, add a $0.1 \mu \mathrm{~F}$ ceramic capacitor from the highside switch drain to the low-side switch source, or add resistors ( $47 \Omega$ max) in series with DL and DH to increase the switches' turn-on and turn-off times (Figure 5).

The minimum load current should exceed the high-side MOSFET's maximum leakage current over temperature if fault conditions are expected.

## Input Capacitor

The input filter capacitor reduces peak currents drawn from the power source and reduces noise and voltage ripple on the input caused by the circuit's switching. The input capacitor must meet the ripple current requirement (IRMS) imposed by the switching currents defined by the following equation:

$$
I_{\mathrm{RMS}}=\mathrm{I}_{\text {LOAD }} \frac{\sqrt{V_{\text {OUT }}\left(\mathrm{V}_{\text {IN }}-V_{\text {OUT }}\right)}}{\mathrm{V}_{\text {IN }}}
$$

For most applications, nontantalum capacitors (ceramic, aluminum, polymer, or OS-CON) are preferred due to their robustness with high inrush currents typical of systems with low-impedance battery inputs. Additionally, two (or more) smaller value low-ESR capacitors can be connected in parallel for lower cost. Choose an input capacitor that exhibits less than $+10^{\circ} \mathrm{C}$ temperature rise at the RMS input current for optimal circuit long-term reliability.

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Figure 5. Reducing the Switching EMI

## Output Capacitor

The key selection parameters for the output capacitor are the actual capacitance value, the equivalent series resistance (ESR), and voltage-rating requirements, which affect the overall stability, output ripple voltage, and transient response.
The output ripple has two components: variations in the charge stored in the output capacitor, and the voltage drop across the capacitor's ESR caused by the current into and out of the capacitor:

$$
V_{\text {RIPPLE }}=V_{R I P P L E(E S R)}+V_{R I P P L E(C)}
$$

The output voltage ripple as a consequence of the ESR and output capacitance is:

$$
\begin{aligned}
& V_{\text {RIPPLE(ESR }}=I_{P-p} E S R \\
& V_{\text {RIPPLE }}(C)=\frac{l_{P-P}}{2 C_{O U T} f_{S W}} \\
& I_{P-P}=\left(\frac{V_{I N}-V_{O U T}}{f_{S W} L}\right)\left(\frac{V_{O U T}}{V_{I N}}\right)
\end{aligned}
$$

where IP-P is the peak-to-peak inductor current (see Inductor Value section). These equations are suitable for initial capacitor selection, but final values should be set by testing a prototype or evaluation circuit. As a general rule, a smaller ripple current results in less output ripple. Since the inductor ripple current is a factor of the inductor value and input voltage, the output voltage ripple decreases with larger inductance but increases with lower input voltages.

With low-cost aluminum electrolytic capacitors, the ESR-induced ripple can be larger than that caused by the current into and out of the capacitor. Consequently, high-quality low-ESR aluminum-electrolytic, tantalum, polymer, or ceramic filter capacitors are required to minimize output ripple. Best results at reasonable cost are typically achieved with an aluminum-electrolytic capacitor in the $470 \mu \mathrm{~F}$ range, in parallel with a $0.1 \mu \mathrm{~F}$ ceramic capacitor.
Since the MAX1864/MAX1865 use a current-mode control scheme, the output capacitor forms a pole that affects circuit stability (see Compensation Design). Furthermore, the output capacitor's ESR also forms a zero.
The MAX1864/MAX1865s' response to a load transient depends on the selected output capacitor. After a load transient, the output instantly changes by ESR $\times$ $\Delta$ LIOAD. Before the controller can respond, the output will sag further, depending on the inductor and output capacitor values.
After a short period of time (see Typical Operating Characteristics), the controller responds by regulating the output voltage back to its nominal state. For applications that have strict transient requirements, low-ESR high-capacitance electrolytic capacitors are recommended to minimize the transient voltage swing.
Do not exceed the capacitor's voltage or ripple-current ratings.

## Compensation Design

The MAX1864/MAX1865 controllers use an internal transconductance error amplifier whose output compensates the control loop. Connect a series resistor and capacitor between COMP and GND to form a polezero pair. The external inductor, high-side MOSFET, output capacitor, compensation resistor, and compensation capacitor determine the loop stability. The inductor and output capacitor are chosen based on performance, size, and cost. Additionally, the compensation resistor and capacitor are selected to optimize control-loop stability. The component values shown in the standard application circuits (Figures 1 and 6) yield stable operation over a broad range of input-to-output voltages.
The controller uses a current-mode control scheme that regulates the output voltage by forcing the required current through the external inductor, so the MAX1864/MAX1865 use the voltage across the highside MOSFET's RDS(ON) to sense the inductor current. Using the current-sense amplifier's output signal and the amplified feedback voltage, the control loop determines the peak inductor current by:

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$$
I_{\text {PEAK }}=\frac{V_{\text {OUT }} V_{\text {REF }} A_{\text {VEA }}}{\left.V_{\text {OUT }}(\text { NOMINAL })^{R} \text { DS(ON }\right)^{A} \text { VCS }}
$$

where AvCS is the current-sense amplifier's gain (4.9 typ), AVEA is the DC gain of the error amplifier (2000 typ), and $\operatorname{VOUT}($ NOMINAL $)$ is the output voltage set by the feedback resistive-divider (internal or external). Since the output voltage is a function of the load current and load resistance, the total DC loop gain $(A \vee(D C))$ is approximately:

$$
\begin{aligned}
A_{V(D C)} \approx \frac{I_{\text {PEAK }}}{L_{\text {LOAD }}} & \approx \frac{V_{\text {REF }} R_{\text {LOAD }} A_{\text {VEA }}}{V_{\text {OUT }}(\text { NOMINAL })^{R_{D S(O N ~}} A_{V C S}} \\
& \approx \frac{400 \times V_{\text {REF }} R_{\text {LOAD }}}{V_{\text {OUT }(\text { NOMINAL }} R_{D S(O N)}}
\end{aligned}
$$

The compensation capacitor (CCOMP) creates the dominant pole. Due to the current-mode control scheme, the output capacitor also creates a pole in the system that is a function of the load resistance. As the load resistance increases, the frequency of the output capacitor's pole decreases. However, the DC loop gain increases with larger load resistance, so the unity gain bandwidth remains fixed. Additionally, the compensation resistor and the output capacitor's ESR both generate zeros. Therefore, to achieve stable operation, use the following procedure to properly compensate the system:

1) First, select the desired crossover frequency. The crossover frequency must be less than both $1 / 5$ th the switching frequency and $1 / 3$ rd the zero frequency set by the output capacitor's ESR:

$$
f_{\mathrm{C}} \leq \frac{1}{6 \pi \mathrm{C}_{\mathrm{OUT}} \mathrm{R}_{\mathrm{ESR}}} \text { and } \frac{f_{\mathrm{SW}}}{5}
$$

2) Next, determine the pole set by the output capacitor and the load resistor:

$$
f_{\mathrm{POLE}(\mathrm{OUT})}=\frac{1}{2 \pi \mathrm{C}_{\mathrm{OUT}} \mathrm{R}_{\mathrm{LOAD}}}=\frac{\mathrm{L}_{\mathrm{LOAD}(\mathrm{MAX})}}{2 \pi \mathrm{C}_{\mathrm{OUT}} \mathrm{~V}_{\mathrm{OUT}}}
$$

3) Determine the compensation resistor required to set the desired crossover frequency:

$$
R_{\mathrm{COMP}}=\frac{2000 \times f_{\mathrm{C}}}{g_{\mathrm{m}} \mathrm{~A}_{\mathrm{V}(\mathrm{DC})} f_{\text {POLE(OUT })}}
$$

where the error amplifier's transconductance ( gm ) is $100 \mu \mathrm{~S}$ (see Electrical Characteristics).
4) Finally, select the compensation capacitor:

$$
\mathrm{C}_{\mathrm{COMP}} \leq \frac{1}{2 \pi \mathrm{R}_{\mathrm{COMP}} f_{\mathrm{POLE}(\mathrm{OUT})}}
$$

Boost-Supply Diode
A signal diode, such as the 1N4148, works well in most applications. If the input voltage goes below 6V, use a small 20 mA Schottky diode for slightly improved efficiency and dropout characteristics. Do not use large power diodes, such as the 1 N5817 or 1 N4001, since high junction capacitance can charge up VL to excessive voltages.

## Linear Regulator Controllers

Positive Output Voltage Selection
The MAX1864/MAX1865s' positive linear regulator output voltages are set by connecting a voltage-divider from the output to FB_ to GND (Figure 6). Select R4 in the $5 \mathrm{k} \Omega$ to $50 \mathrm{k} \Omega$ range. Calculate R 3 with the following equation:

$$
\mathrm{R} 3=\mathrm{R} 4\left[\left(\frac{\mathrm{~V}_{\mathrm{OUT}}}{\mathrm{~V}_{\mathrm{FB}}}\right)-1\right]
$$

where $\mathrm{V}_{\mathrm{FB}}=1.24 \mathrm{~V}$, and $\mathrm{V}_{\text {OUT }}$ may range from 1.24 V to 30V.

Negative Output Voltage Selection (MAX1865)
The MAX1865's negative output voltage is set by connecting a voltage-divider from the output to FB5 to a positive voltage reference (Figure 6). Select R6 in the $5 \mathrm{k} \Omega$ to $50 \mathrm{k} \Omega$ range. Calculate R5 with the following equation:

$$
\mathrm{R} 5=\mathrm{RG}\left(\frac{\mathrm{~V}_{\mathrm{OUT}}}{\mathrm{~V}_{\mathrm{REF}}}\right)
$$

where $\mathrm{V}_{\text {REF }}$ is the positive reference voltage used, and Vout may be set between 0 and -20 V .
If the negative regulator is used, the OUT pin must be connected to a voltage supply between 2 V and 5 V that can source at least 25 mA . Typically, the OUT pin is connected to the step-down converter's output. However, if the step-down converter's output voltage is set higher than 5 V , OUT may be connected to one of the positive linear regulators with an output voltage between 2 V and 5 V .

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Figure 6. Standard MAX1865 Application Circuit

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## Transistor Selection

The pass transistors must meet specifications for current gain (hFE), input capacitance, collector-emitter saturation voltage, and power dissipation. The transistor's current gain limits the guaranteed maximum output current to:

$$
\operatorname{LOAD}(\mathrm{MAX})=\left[\operatorname{ldRV}-\left(\frac{V_{B E}}{R_{B E}}\right)\right] h_{\text {FE(MIN) }}
$$

where IDRV is the minimum base-drive current, and RBE (220 $)$ ) is the pullup resistor connected between the transistor's base and emitter. Furthermore, the transistor's current gain increases the linear regulator's DC loop gain (see Stability Requirements), so excessive gain will destabilize the output. Therefore, transistors with current gain over 100 at the maximum output current, such as Darlington transistors, are not recommended. The transistor's input capacitance and input resistance also create a second pole, which could be low enough to destabilize the output when heavily loaded.
The transistor's saturation voltage at the maximum output current determines the minimum input-to-output voltage differential that the linear regulator will support. Alternatively, the package's power dissipation could limit the useable maximum input-to-output voltage differential. The maximum power dissipation capability of the transistor's package and mounting must exceed the actual power dissipation in the device. The power dissipated equals the maximum load current times the maximum input-to-output voltage differential:

$$
P=\operatorname{LOAD}(\operatorname{MAX})\left(\mathrm{V}_{\text {LDOIN }}-V_{\text {OUT }}\right)=\operatorname{LOAD(MAX)} V_{C E}
$$

## Stability Requirements

The MAX1864/MAX1865 linear regulators use an internal transconductance amplifier to drive an external pass transistor. The transconductance amplifier, pass transistor's specifications, the base-emitter resistor, and the output capacitor determine the loop stability. If the output capacitor and pass transistor are not properly selected, the linear regulator will be unstable.
The transconductance amplifier regulates the output voltage by controlling the pass transistor's base current. Since the output voltage is a function of the load current and load resistance, the total DC loop gain ( $\mathrm{A} \vee(\mathrm{LDO})$ ) is approximately:

$$
\mathrm{A}_{\mathrm{V}(\mathrm{LDO})} \approx\left(\frac{5.5}{\mathrm{~V}_{\mathrm{T}}}\right)\left[1+\left(\frac{\mathrm{I}_{\mathrm{BIAS}} \mathrm{~h}_{\mathrm{FE}}}{\mathrm{l}_{\mathrm{LOAD}}}\right)\right] \mathrm{V}_{\mathrm{REF}}
$$

where $\mathrm{V}_{\mathrm{T}}$ is 26 mV , and $\mathrm{I}_{\mathrm{BIAS}}$ is the current through the base-to-emitter resistor (RBE). This bias resistor is typically $220 \Omega$, providing approximately 3.2 mA of bias current.
The output capacitor creates the dominant pole. However, the pass transistor's input capacitance creates a second pole in the system. Additionally, the output capacitor's ESR generates a zero, which may be used to cancel the second pole if necessary. Therefore, to achieve stable operation, use the following equations to verify that the linear regulator is properly compensated:

1) First, determine the dominant pole set by the linear regulator's output capacitor and the load resistor:

$$
f_{\mathrm{POLE}(\mathrm{CLDO})}=\frac{1}{2 \pi \mathrm{C}_{\mathrm{LDO}} \mathrm{R}_{\mathrm{LOAD}}}=\frac{\mathrm{l}_{\mathrm{LOAD}(\mathrm{MAX})}}{2 \pi \mathrm{C}_{\mathrm{LDO}} \mathrm{~V}_{\mathrm{LDO}}}
$$

Unity Gain Crossover $=\mathrm{A}_{\mathrm{V}(\mathrm{LDO})} \mathrm{f}_{\mathrm{POLE}(\mathrm{CLDO})}$
2) Next, determine the second pole set by the base-toemitter capacitance (including the transistor's input capacitance), the transistor's input resistance, and the base-to-emitter pullup resistor:

$$
\begin{aligned}
f_{\mathrm{POLE}(\mathrm{CBE})} & =\frac{1}{2 \pi \mathrm{C}_{\mathrm{BE}}\left(\mathrm{R}_{\mathrm{BE}}\| \|_{\mathrm{R}}(\mathrm{NPN})\right.} \text { ) } \\
& =\frac{\mathrm{R}_{\mathrm{BE}} L_{L O A D}+\mathrm{V}_{\mathrm{T}} h_{F E}}{2 \pi \mathrm{C}_{\mathrm{BE}} \mathrm{R}_{\mathrm{BE}} \mathrm{~V}_{\top} h_{F E}}
\end{aligned}
$$

3) A third pole is set by the linear regulator's feedback resistance and the capacitance between FB_ and GND, including 20pF stray capacitance:

$$
f_{\mathrm{POLE}(\mathrm{FB})}=\frac{1}{2 \pi \mathrm{CFB}(\mathrm{R} 1 \| \mathrm{R} 2)}
$$

4) If the second and third poles occur well after unitygain crossover, the linear regulator will remain stable:

$$
f_{\text {POLE }}(\mathrm{CBE})>2 f_{\text {POLE(CLDO }} \mathrm{A}_{\mathrm{V}(\text { LDO })}
$$

However, if the ESR zero occurs before unity-gain crossover, cancel the zero with $f$ POLE(FB) by changing circuit components such that:

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$$
f_{\mathrm{POLE}(\mathrm{FB})} \approx \frac{1}{2 \pi \mathrm{C}_{\mathrm{OUT}} \mathrm{R}_{\mathrm{ESR}}}
$$

Do not use output capacitors with more than $200 \mathrm{~m} \Omega$ of ESR. Typically, more output capacitance provides the best solution, since this also reduces the output voltage drop immediately after a load transient.

## Linear Regulator Output Capacitors

Connect at least a $1 \mu \mathrm{~F}$ capacitor between the linear regulator's output and ground, as close to the MAX1864/MAX1865 and external pass transistors as possible. Depending on the selected pass transistor, larger capacitor values may be required for stability (see Stability Requirements). Furthermore, the output capacitor's ESR affects stability, providing a zero that may be necessary to cancel the second pole. Use output capacitors with an ESR less than $200 \mathrm{~m} \Omega$ to ensure stability and optimum transient response.
Once the minimum capacitor value for stability is determined, verify that the linear regulator's output does not contain excessive noise. Although adequate for stability, small capacitor values may provide too much bandwidth, making the linear regulator sensitive to noise. Larger capacitor values reduce the bandwidth, thereby reducing the regulator's noise sensitivity.
If noise on the ground reference causes the design to be marginally stable for the negative linear regulator, bypass the negative output back to its reference voltage ( $V_{\text {REF }}$, Figure 7). This technique reduces the differential noise on the output.

## Base-Drive Noise Reduction

The high-impedance base driver is susceptible to system noise, especially when the linear regulator is lightly loaded. Capacitively coupled switching noise or inductively coupled EMI onto the base drive causes fluctuations in the base current, which appear as noise on the linear regulator's output. Keep the base-drive traces away from the step-down converter and as short as possible to minimize noise coupling. Resistors in series with the gate drivers ( DH and DL ) reduce the LX switching noise generated by the step-down converter (Figure 5). Additionally, a bypass capacitor may be placed across the base-to-emitter resistor (Figure 7). This bypass capacitor, in addition to the transistor's input capacitance, could bring in a second pole that will destabilize the linear regulator (see Stability Requirements). Therefore, the stability requirements determine the maximum base-to-emitter capacitance:

a) POSITIVE OUTPUT VOLTAGE


Figure 7. Base-Drive Noise Reduction

$$
\mathrm{C}_{\mathrm{BE}} \leq \frac{1}{2 \pi f_{\mathrm{POLE}(\mathrm{CBE})}}\left(\frac{\mathrm{R}_{\mathrm{BE}} \mathrm{~L}_{\mathrm{LOAD}}+\mathrm{V}_{\mathrm{T}} \mathrm{~h}_{\mathrm{FE}}}{\mathrm{R}_{\mathrm{BE}} \mathrm{~V}_{\mathrm{T}} \mathrm{~h}_{\mathrm{FE}}}\right)-\mathrm{C}_{\mathrm{IN}(\mathrm{Q})}
$$

where $\operatorname{CIN}(Q)$ is the transistor's input capacitance, and fPOLE(CBE) is the second pole required for stability.

## Transformer Selection

In systems where the step-down controller's output is not the highest voltage, a transformer may be used to provide additional postregulated, high-voltage outputs. The transformer generates unregulated, high-voltage supplies that power the positive and negative linear regulators. These unregulated supply voltages must be high enough to keep the pass transistors from saturating. For positive output voltages, connect the transformer as shown in figure 6 where the minimum turns ratio $(N)$ is determined by:

$$
\mathrm{NPOS} \geq\left(\frac{\mathrm{V}_{\mathrm{LDO}(\mathrm{POS})}+\mathrm{V}_{\mathrm{SAT}}+\mathrm{V}_{\mathrm{DIODE}}}{\mathrm{~V}_{\mathrm{OUT}}}-1\right)
$$

where VSAT is the pass transistor's saturation voltage under full load. For negative output voltages (MAX1865

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only), connect the transformer as shown in Figure 6, where the minimum turns ratio is determined by:

$$
N_{\mathrm{NEG}} \geq\left(\frac{\left|\mathrm{V}_{\mathrm{LDO}(\mathrm{NEG})}\right|+\mathrm{V}_{\mathrm{SAT}}+\mathrm{V}_{\mathrm{DIODE}}}{\mathrm{~V}_{\mathrm{OUT}}}\right)
$$

Since power transfer occurs when the low-side MOSFET is on (DL = high), the transformer cannot support heavy loads with high duty cycles.

## Snubber Design

The MAX1864/MAX1865 use a current-mode control scheme that senses the current across the high-side MOSFET ( NH ). Immediately after the high-side MOSFET has turned on, the MAX1864/MAX1865 use a 60ns cur-rent-sense blanking period to minimize noise sensitivity. When the MOSFET turns on, however, the transformer's secondary inductance and the diode's parasitic capacitance form a resonant circuit that causes ringing. Reflected back through the transformer to the primary side, these oscillations across the high-side MOSFET may last longer than the blanking period. A series RC snubber circuit at the diode (Figure 6) increases the damping factor, allowing the ringing to settle quickly. Applications with multiple transformer windings require only one snubber circuit on the highest output voltage. Applications with low turn ratios (1:1), such as the MAX1864 typical application circuit (Figure 1), may not require a snubber curcuit.
The diode's parasitic capacitance can be estimated using the diode's reverse voltage rating (VRRM), current capability (IO), and recovery time (TRR). A rough approximation is:

$$
\mathrm{C}_{\text {DIODE }}=\frac{\mathrm{l} \times \mathrm{t}_{\mathrm{RR}}}{\mathrm{~V}_{\text {RRM }}}
$$

For the EC10QS10 Nihon diode used in figure 6, the capacitance is roughly 15 pF . The output snubber must only dampen the ringing, so the initial turn-on spike that occurs during the blanking period remains preset. A 100pF capacitor works well in most applications; larger capacitance values require more charge, thereby increasing the power dissipation.
The snubber's time constant (tSNUB) must be smaller than the 100ns blanking time. A typical RC time constant of approximately 30ns was chosen for Figure 6:

$$
\mathrm{R}_{\text {SNUB }}=\frac{\mathrm{t}_{\text {SNUB }}}{\mathrm{C}_{\text {SNUB }}}=\frac{30 \mathrm{~ns}}{\mathrm{C}_{\text {SNUB }}}
$$

## Minimum Load Requirements (Linear Regulators)

Under no-load conditions, leakage currents from the pass transistors supply the output capacitor, even when the transistor is off. Generally, this is not a problem since the feedback resistors' current drains the excess charge. However, charge may build up on the output capacitor over temperature, making VLDO rise above its set point. Care must be taken to ensure that the feedback resistors' current exceeds the pass transistor's leakage current over the entire temperature range.

## Applications Information

## PC Board Layout Guidelines

Careful PC board layout is critical to achieve low switching losses and clean, stable operation. The switching power stage requires particular attention. Follow these guidelines for good PC board layout:

1) Place the power components first, with ground terminals adjacent ( NL source, $\mathrm{CIN}, \mathrm{CoUT}$ ). If possible, make all these connections on the top layer with wide, copper-filled areas. Keep these high-current paths short, especially at ground terminals.
2) Mount the MAX1864/MAX1865 adjacent to the switching MOSFETs to keep IN-LX current-sense lines, LX-GND current-limit sense lines, and the driver lines ( DL and DH ) short and wide. The currentsense amplifier inputs are connected between IN and $L X$, so these pins must be connected as close as possible to the high-side MOSFET. The currentlimit comparator inputs are connected between LX and GND, but accuracy is not as important, so give priority to the high-side MOSFET connections. The IN, LX, and GND connections to the MOSFETs must be made using Kelvin sense connections to guarantee current-sense and current-limit accuracy.
3) Group the gate-drive components (BST diode and capacitor, IN bypass capacitor) together near the MAX1864/MAX1865.
4) All analog grounding must be done to a separate solid copper ground plane, which connects to the MAX1864/MAX1865 at the GND pin. This includes the VL bypass capacitor, feedback resistors, compensation components (RCOMP, CCOMP), and adjustable current-limit threshold resistors connected to ILIM.

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5) Ensure all feedback connections are short and direct. Place the feedback resistors as close to the MAX1864/MAX1865 as possible.
6) When trade-offs in trace lengths must be made, it's preferable to allow the inductor charging path to be made longer than the discharge path. For example, it is better to allow some extra distance between the input capacitors and the high-side MOSFET than to allow distance between the inductor and low-side MOSFET or between the inductor and output filter capacitor.
7) Route high-speed switching nodes away from sensitive analog areas ( $B_{-}, F_{-}$, COMP, ILIM).

Regulating High Voltage
The linear regulator controllers can be configured to regulate high output voltages by adding a cascode transistor to buffer the base-drive output. For example, to generate an output voltage between 30 V and 60 V , add a 2N5550 high-voltage NPN transistor as shown in Figure 8a where VBIAS is a DC voltage between 3 V and 20 V that can source at least 1 mA . RDROP protects the cascode transistor by decreasing the voltage across the transistor when the pass transistor saturates. Similarly, to regulate a negative output voltage between -20 V and -120V, add a 2N5401 high-voltage PNP transistor as shown in Figure 8b.


Chip Information
TRANSISTOR COUNT: 1617
PROCESS: BiCMOS

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Figure 8. High-Voltage Linear Regulation
Table 1. Component Suppliers

| SUPPLIER | PHONE | FAX | INTERNET |
| :---: | :---: | :---: | :---: |
| INDUCTORS AND TRANSFORMERS |  |  |  |
| Coilcraft | 847-639-6400 | 847-639-1469 | http://www.coilcraft.com |
| Coiltronics | 561-241-7876 | 561-241-9339 | http://www.coiltronics.com |
| Sumida USA | 847-956-0666 | 847-956-0702 | http://www.sumida.com |
| Toko | 847-297-0070 | 847-699-1194 | http://www.toko.co.jp |
| CAPACITORS |  |  |  |
| AVX | 803-946-0690 | 803-626-3123 | http://www.avxcorp.com |
| Kemet | 408-986-0424 | 408-986-1442 | http://www.kemet.com |
| Panasonic | 847-468-5624 | 847-468-5815 | http://www.panasonic.com |
| Sanyo | 619-661-6835 | 619-661-1055 | http://www.sanyo.com |
| Taiyo Yuden | 408-573-4150 | 408-573-4159 | http://www.t-yuden.com |
| DIODES |  |  |  |
| Central Semiconductor | 516-435-1110 | 516-435-1824 | http://www.centralsemi.com |
| International | 310-322-3331 | 310-322-3332 | http://www.irf.com |
| Nihon | 847-843-7500 | 847-843-2798 | http://www.niec.co.jp |
| On Semiconductor | 602-303-5454 | 602-994-6430 | http://www.onsemi.com |
| Zetex | 516-543-7100 | 516-864-7630 | http://www.zetex.com |

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